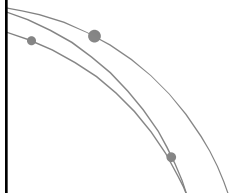


Capacitance and Resistance

Sandra Cruz-Pol, Ph. D.
INEL 4151
Electromagnetics I
ECE UPRM
Mayagüez, PR

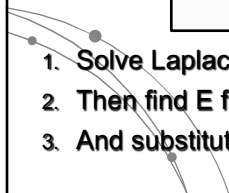


Resistance

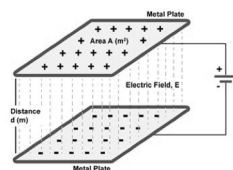
- If the cross section of a conductor is not uniform we need to integrate:

$$R = \frac{V}{I} = \frac{\int_s \vec{E} \cdot d\vec{l}}{\int_s \sigma \vec{E} \cdot d\vec{S}} \quad R = \frac{V}{I} = \frac{V}{\int_s \sigma \vec{E} \cdot d\vec{S}}$$

1. Solve Laplace eq. to find V
2. Then find E from its differential
3. And substitute in the above equation



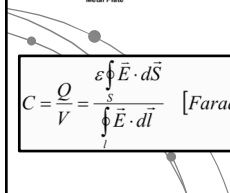
Capacitance



- Is defined as the ratio of the charge on one of the plates to the potential difference between the plates:

1. Assume Q and find V (Gauss or Coulomb)
2. Assume V and find Q (Laplace)
3. And substitute E in the equation.

$$C = \frac{Q}{V} = \frac{\int_s \vec{E} \cdot d\vec{S}}{\int_l \vec{E} \cdot d\vec{l}} \quad [\text{Farads}]$$



To find E, we will use:

from Gauss's Law

$$\begin{aligned} \nabla \cdot D &= \nabla \cdot \epsilon E = \rho_v \\ E &= -\nabla V \end{aligned}$$

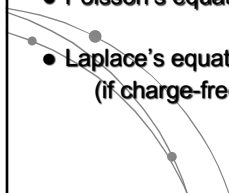
From this we can get:

- Poisson's equation:

$$\nabla^2 V = -\frac{\rho_v}{\epsilon}$$

- Laplace's equation: (if charge-free)

$$\nabla^2 V = 0$$



Relaxation Time

- Recall that:

$$R = \frac{V}{I} = \frac{V}{\int_s \sigma \vec{E} \cdot d\vec{S}} \quad C = \frac{Q}{V} = \frac{\int_s \vec{E} \cdot d\vec{S}}{\int_l \vec{E} \cdot d\vec{l}} \quad [\text{Farads}]$$

- Multiplying, we obtain the Relaxation Time:

$$RC = \frac{\epsilon}{\sigma}$$

- Solving for R, we obtain it in terms of C:

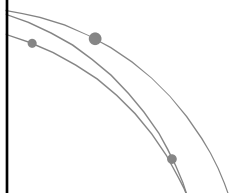
$$R = \frac{\epsilon}{\sigma C}$$



P.E. 6.8 find Resistance of disk of radius b and central hole of radius a.

Laplace's equation:
In cylindrical coordinates (if charge-free)

$$\nabla^2 V = \frac{1}{\rho} \frac{\partial}{\partial \rho} \left(\rho \frac{\partial V}{\partial \rho} \right) + \frac{1}{\rho^2} \frac{\partial^2 V}{\partial \phi^2} + \frac{\partial^2 V}{\partial z^2} = 0$$



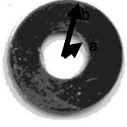
P.E. 6.8 find Resistance of disk of radius b and central hole of radius a .

$$\frac{1}{\rho} \frac{\partial}{\partial \rho} \left(\rho \frac{\partial V}{\partial \rho} \right) + \frac{1}{\rho^2} \frac{\partial^2 V}{\partial \phi^2} + \frac{\partial^2 V}{\partial z^2} = 0 \quad \frac{1}{\rho} \frac{\partial}{\partial \rho} \left(\rho \frac{\partial V}{\partial \rho} \right) = 0$$

$$V = A \ln \rho + B \quad BC: \left. \begin{array}{l} V(\rho=a)=0 \\ V(\rho=b)=V_o \end{array} \right\} V = \frac{V_o}{\ln(b/a)} \ln \frac{\rho}{a}$$

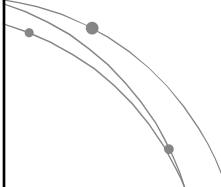
$$E = -\nabla V = -\frac{dV}{d\rho} \hat{\rho} = \frac{V_o}{\rho \ln(b/a)} \hat{\rho} \quad d\vec{S} = -\rho dz d\phi \hat{\rho}$$

$$I = \oint_S \sigma \vec{E} \cdot d\vec{S} = \frac{2\pi V_o \sigma}{\ln(b/a)}$$

$$R = \frac{V_o}{I} = \frac{V_o}{\oint_S \sigma \vec{E} \cdot d\vec{S}} = \frac{\ln(b/a)}{2\pi \sigma t}$$


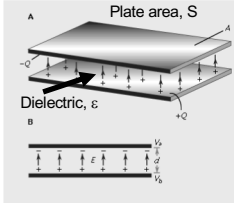
Capacitance

1. Parallel plate
2. Coaxial
3. Spherical

$$C = \frac{Q}{V} = \frac{Q}{\oint_0^L \vec{E} \cdot d\vec{l}}$$


Parallel plate Capacitor

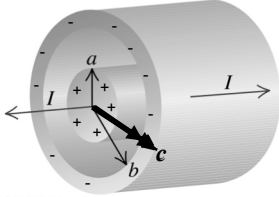
- Charge Q and $-Q$

$$\rho_s = \frac{Q}{S} \quad \vec{D}_n = \rho_s \hat{a}_x \quad \vec{E} = \frac{\rho_s}{\epsilon} \hat{a}_x$$


$$V = -\int_d^0 \vec{E} \cdot d\vec{l} = -\int_d^0 \frac{Q}{\epsilon S} dx = \frac{Qd}{\epsilon S} \quad C = \frac{Q}{V} = \frac{\epsilon S}{d}$$

Coaxial Capacitor

- Charge $+Q$ & $-Q$

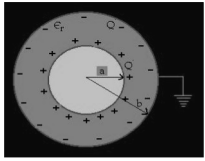
$$Q = \epsilon \oint \vec{E} \cdot d\vec{S} = \epsilon E_\rho 2\pi \rho L$$


$$V = -\int \vec{E} \cdot d\vec{l} = -\int_b^a \frac{Q}{2\pi \epsilon \rho L} \hat{\rho} \cdot d\rho \hat{\rho} = \frac{Q}{2\pi \epsilon L} \ln \frac{b}{a}$$

$$C = \frac{Q}{V} = \frac{2\pi \epsilon L}{\ln \frac{b}{a}}$$

Spherical Capacitor

- Charge $+Q$ & $-Q$

$$Q = \epsilon \oint \vec{E} \cdot d\vec{S} = \epsilon E_r 4\pi r^2$$


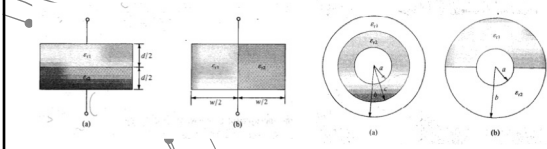
$$V = -\int \vec{E} \cdot d\vec{l} = -\int_b^a \frac{Q}{4\pi \epsilon r^2} \hat{r} \cdot dr \hat{r} = \frac{Q}{4\pi \epsilon} \left[\frac{1}{a} - \frac{1}{b} \right]$$

$$C = \frac{Q}{V} = \frac{4\pi \epsilon}{\left[\frac{1}{a} - \frac{1}{b} \right]}$$

Capacitors connection

- Series $\frac{1}{C} = \frac{1}{C_1} + \frac{1}{C_2}$
- Parallel $C = C_1 + C_2$

Examples:



In summary :

	C	R	
Parallel Plate	$\frac{\epsilon S}{d}$	$\frac{\sigma d}{S}$	
Coaxial	$\frac{2\pi\epsilon L}{\ln \frac{b}{a}}$	$\frac{2\pi\epsilon L}{\ln \frac{b}{a}}$	
Spherical	$\frac{4\pi\epsilon}{\left[\frac{1}{a} - \frac{1}{b}\right]}$		

Method of Images

- (or mirror charges) is a problem-solving tool in electrostatics.

(a) Perfectly conducting plane $V = 0$

(b) Equipotential surface $V = 0$

Method of Images

- Use superposition
- Valid only for top region (where Q is)

$$V(\rho, \varphi, z) = \frac{1}{4\pi\epsilon_0} \left(\frac{q}{\sqrt{\rho^2 + (z-a)^2}} + \frac{-q}{\sqrt{\rho^2 + (z+a)^2}} \right)$$